NSN 5961-01-033-0822

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Inclosure Material:

Metal

Overall Length:

Between 0.250 inches and 0.450 inches

Overall Diameter:

0.875 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

125.0 breakdown voltage, collector-to-base, emitter open and 75.0 breakdown voltage, collector-to-emitter, base open and 7.0

breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

Between 5.00 amperes source cutoff current and 20.00 amperes source cutoff current

Power Rating Per Characteristic:

6.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

2 uninsulated wire lead and 1 case

Specification Data:

81349-mil-s-19500/439 government specification

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig: